NSN 5961-01-143-2530

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-143-2530 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 drain to gate voltage and 35.0 drain to source voltage and 15.0 forward gate to source voltage **Current Rating Per Characteristic:** 3.00 amperes peak pulse current and 2.00 milliamperes forward gate current **Power Rating Per Characteristic:** 8.33 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Burn-in **Test Data Document:** 96214-808382 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**